## THYRISTOR MODULE AK55HB120/160



UL;E76102 (M)

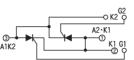
Power ThyristorModule AK55HB series are designed for various rectifier circuits and power controls. For your circuit application. following internal connections and wide voltage ratings up to 1600V are available, and electrically isolated mounting base make your mechanical design easy.

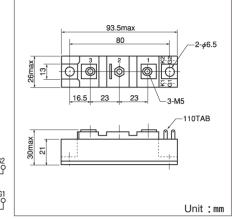
Isolated mounting base

- IT (AV) 55A, IT (RMS) 122A, ITSM 1100A
- di/dt 150 A/ μs dv/dt 500V/ μs

(Applications) AC/DC motor drives Heater controls Light dimmers Static switches

Internal Configurations





Maximum Ratings

 $(Tj=25^{\circ}C \text{ unless otherwise specified})$ 

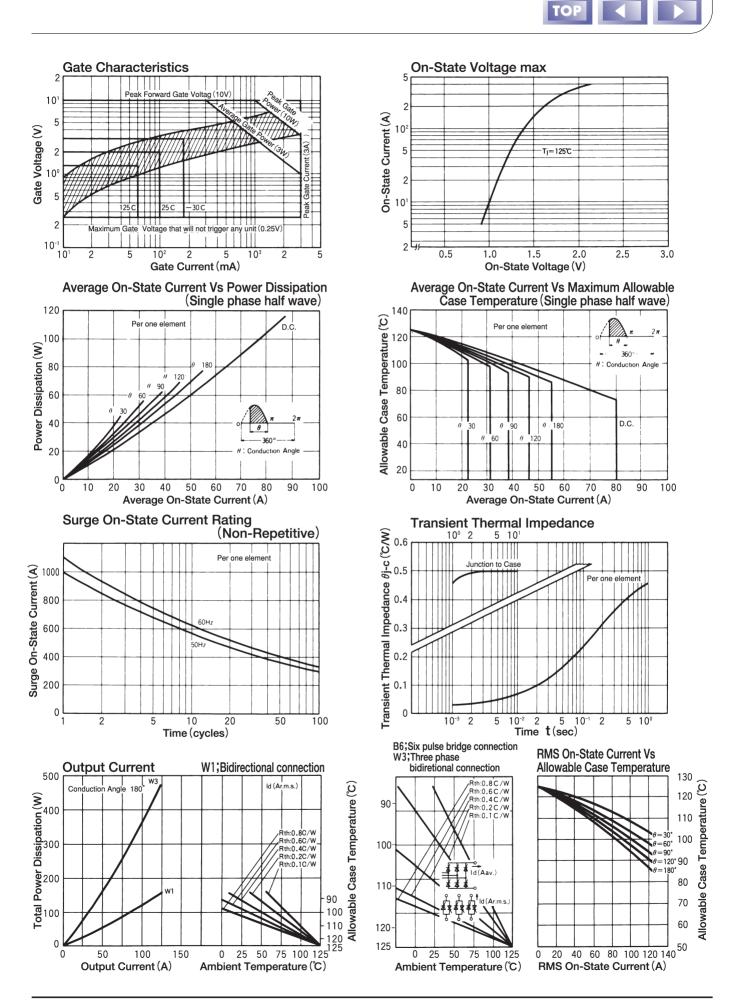
Symbol	Itom	Ratings		Unit
	Item	AK55HB120	AK55HB160	Unit
Vdrm	Repetitive Peak Off-State Voltage	1200	1600	V

Symbol		Item	Conditions	Ratings	Unit
IT (AV)	Average On	-State Current	Single phase, half wave, 180° conduction, Tc:85℃	55	Α
IT (RMS)	R.M.S. On-S	State Current	Current Tc:85°C		Α
Ітѕм	Surge On-S	tate Current	<sup>1</sup> / <sub>2</sub> cycle, 50Hz/60Hz, peak value, non-reqetitive	1000/1100	Α
l²t	l²t		Value for one cycle of surge current	5000	A <sup>2</sup> S
Рдм	Peak Gate Power Dissipation			10	W
PG (AV)	Average Gate Power Dissipation			3	W
IFGM	Peak Gate Current			3	Α
VFGM	Peak Gate Voltage (Forwad)			10	V
VRGM	Peak Gate Voltage (Reverse)			5	V
di/dt	Critical Rate of Rise of On-State Current		IG=100mA,Tj=25°C,VD=1/2VDRM,dIG/dt=0.1A/µs	150	A/µs
Viso	Isolation Breakdown Voltage (R.M.S.)		A.C. 1 minute	2500	V
Tj	Operating Junction Temperature			-40~+125	°C
Tstg	Storage Temperature			-40~+125	°C
	Mounting Torque	Mounting (M6)	Recommended Value 2.5~3.9 (25~40)	4.7 (48)	N∙m
		Terminal (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	(kgf·cm)
	Mass		Typical Value	170	g

## Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit	
<b>I</b> DRM	Repetitive Peak Off-State Current, max.	at VDRM, Single phase, half wave, Tj=125℃	20	mA	
Vтм	Peak On-State Voltage max.	On-State Current 165A, Tj=125°CInst. measurement	1.50	V	
Igt/Vgt	Gate Trigger Current/Voltage, max.	Tj=25℃, I⊤=1A, V□=6V	100/2	mA/V	
Vgd	Non-Trigger Gate, Voltage. min.	Тј=125℃, VD=½VDRM	0.25	V	
tgt	Turn On Time, max.	IT=55A, IG=100mA, Tj=25°C, VD=1/2VDRM, dIg/dt=0.1A/µs	10	μs	
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	Tj=125℃, VD=⅔VDRм, Exponential wave.	500	V/µs	
Ін	Holding Current, typ.	Tj=25℃	50	mA	
IL.	Lutching Current, typ.	Tj=25℃	100	mA	
Rth (j-c)	Thermal Impedance, max.	Junction to case, per 1/2 Module	0.50	°0 / M	
		Junction to case, per 1 Module	0.25	- °C/₩	

## SanRex



SANSHA ELECTRIC

AK55HB120/160